

RoHS Compliant Product

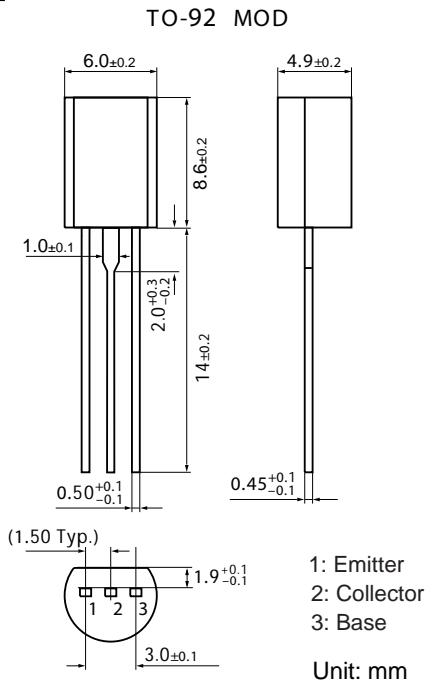
A suffix of "-C" specifies halogen & lead-free

FEATURE

Power Amplifier Applications

MAXIMUM RATINGS Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CB0}	Collector-Base Voltage	-50	V
V _{CE0}	Collector-Emitter Voltage	-50	V
V _{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-2	A
P _D	Total Power Dissipation	900	mW
T _J , T _{stg}	Junction and Storage Temperature	-55~+150	°C



ELECTRICAL CHARACTERISTICS Tamb=25°C unless otherwise specified

Parameter	Symbol	Min	Typ.	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage	V(BR)CBO	-50	-	-	V	I _C =-100μA, I _E =0
Collector-Emitter Breakdown Voltage	V(BR)CEO	-50	-	-	V	I _C =-1 mA, I _B =0
Emitter-Base Breakdown Voltage	V(BR)EBO	-5	-	-	V	I _E =-100μA, I _C =0
Collector-Base Cutoff Current	I _{CBO}	-	-	-1	uA	V _{CB} =-50V, I _E =0
Emitter-Base Cutoff Current	I _{EBO}	-	-	-1	uA	V _{BE} =-5V, I _C =0
Collector Saturation Voltage	V _{CE(sat)}	-	-	-0.5	V	I _C =-1A, I _B =-50mA
Base Saturation Voltage	V _{BE(sat)}	-	-	-1.2	V	I _C =-1A, I _B =-50mA
DC Current Gain	h _{FE1}	70	-	240		V _{CE} =-2V, I _C =-500A
Gain-Bandwidth Product	f _T	-	100	-	MHz	V _{CE} =-2V, I _C =-500mA
Output Capacitance	C _{ob}	-	40	-	pF	V _{CB} =-10V, f=1MHz

Classification of hFE1

Rank	O	Y
Range	70~140	120~240

Typical Characteristics

2SA1020

